Quad 2-Input OR Gate

MC74VHC32

The MC74VHC32 is an advanced high speed CMOS 2–input OR gate fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining CMOS low power dissipation.

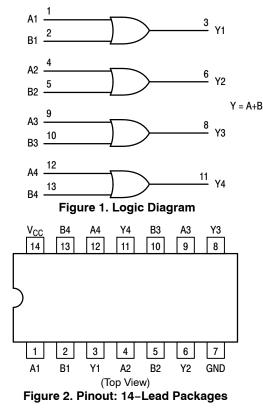
The internal circuit is composed of three stages, including a buffer output which provides high noise immunity and stable output. The inputs tolerate voltages up to 7.0 V, allowing the interface of 5.0 V systems to 3.0 V systems.

Features

- High Speed: $t_{PD} = 3.8 \text{ ns} (Typ) \text{ at } V_{CC} = 5.0 \text{ V}$
- Low Power Dissipation: $I_{CC} = 2.0 \ \mu A$ (Max) at $T_A = 25^{\circ}C$
- High Noise Immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$
- Power Down Protection Provided on Inputs
- Balanced Propagation Delays
- Designed for 2.0 V to 5.5 V Operating Range
- Low Noise: $V_{OLP} = 0.8 V (Max)$
- Pin and Function Compatible with Other Standard Logic Families
- Latchup Performance Exceeds 300 mA
- ESD Performance:

Human Body Model > 2000 V; Machine Model > 200 V

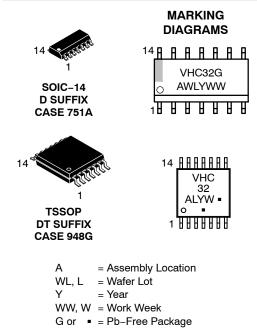
- Chip Complexity: 48 FETs or 12 Equivalent Gates
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant



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(Note: Microdot may be in either location)

FUNCTION TABLE

Inputs		Output
Α	В	Y
L	L	L
L	н	н
Н	L	н
Н	Н	Н

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

1

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
V _{CC}	DC Supply Voltage		-0.5 to +7.0	V
V _{in}	DC Input Voltage		-0.5 to +7.0	V
V _{out}	DC Output Voltage	–0.5 to V _{CC} +0.5	V	
Ι _{ΙΚ}	Input Diode Current	-20	mA	
I _{ОК}	Output Diode Current	±20	mA	
I _{out}	DC Output Current, per Pin		±25	mA
I _{CC}	DC Supply Current, V _{CC} and GND Pins		±50	mA
PD	Power Dissipation in Still Air,	SOIC Package [†] TSSOP Package [†]	500 450	mW
T _{stg}	Storage Temperature		–65 to +150	°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range GND $\leq (V_{in} \text{ or } V_{out}) \leq V_{CC}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

†Derating – SOIC Package: – 7 mW/°C from 65° to 125°C TSSOP Package: – 6.1 mW/°C from 65° to 125°C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
V _{CC}	DC Supply Voltage		2.0	5.5	V
V _{in}	DC Input Voltage		0	5.5	V
V _{out}	DC Output Voltage		0	V _{CC}	V
T _A	Operating Temperature		-40	+125	°C
t _r , t _f	Input Rise and Fall Time	V _{CC} = 3.3 V ±0.3 V V _{CC} = 5.0 V ±0.5 V	0 0	100 20	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

			V _{cc}	T _A = 25°C		T _A = −40°0	C to 125°C		
Symbol	Parameter	Test Conditions	V	Min	Тур	Max	Min	Max	Unit
V _{IH}	Minimum High-Level Input Voltage		2.0 3.0 to 5.5	1.50 V _{CC} x 0.7			1.50 V _{CC} x 0.7		V
V _{IL}	Maximum Low-Level Input Voltage		2.0 3.0 to 5.5			0.50 V _{CC} x 0.3		0.50 V _{CC} x 0.3	V
V _{OH}	Minimum High-Level Output Voltage	$V_{in} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -50 \ \mu A$	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5		1.9 2.9 4.4		V
		$V_{in} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -4.0 \text{ mA}$ $I_{OH} = -8.0 \text{ mA}$	3.0 4.5	2.58 3.94			2.48 3.80		
V _{OL}	Maximum Low-Level Output Voltage	$V_{in} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 50 \ \mu A$	2.0 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.1		0.1 0.1 0.1	V
		$V_{in} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 4.0 \text{ mA}$ $I_{OL} = 8.0 \text{ mA}$	3.0 4.5			0.36 0.36		0.44 0.44	
l _{in}	Maximum Input Leakage Current	V _{in} = 5.5 V or GND	0 to 5.5			±0.1		±1.0	μΑ
Icc	Maximum Quiescent Supply Current	$V_{in} = V_{CC}$ or GND	5.5			2.0		20.0	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$)

		$T_{A} = 25^{\circ}C$ $T_{A} = -40^{\circ}C$ to 125°C		T _A = 25°C		C to 125°C		
Symbol	Parameter	Test Conditions	Min	Тур	Max	Min	Max	Unit
t _{PLH} , t _{PHL}	Maximum Propagation Delay,	$\label{eq:VCC} \begin{array}{l} V_{CC} = 3.3 \pm 0.3 \; VC_{L} = 15 \; pF \\ C_{L} = 50 \; pF \end{array}$		5.5 8.0	7.9 11.4	1.0 1.0	9.5 13.0	ns
	A or B to Y	$\label{eq:VCC} \begin{array}{l} V_{CC} = 5.0 \pm 0.5 \; VC_L = 15 \; pF \\ C_L = 50 \; pF \end{array}$		3.8 5.3	5.5 7.5	1.0 1.0	6.5 8.5	
C _{in}	Maximum Input Capacitance			4	10		10	pF

		Typical @ 25°C, V _{CC} = 5.0 V	
C _{PD}	Power Dissipation Capacitance (Note 1)	14	pF

1. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}/4$ (per gate). C_{PD} is used to determine the no–load dynamic power consumption; $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$.

			T _A = 25°C	
Symbol	Characteristic	Тур	Max	Unit
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	0.3	0.8	V
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}		-0.8	V
V _{IHD}	Minimum High Level Dynamic Input Voltage		3.5	V
V _{ILD}	Maximum Low Level Dynamic Input Voltage		1.5	V

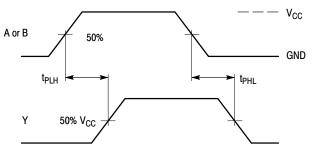
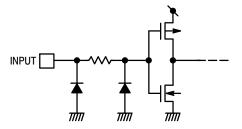
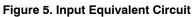
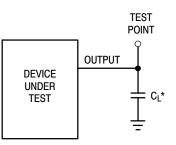


Figure 3. Switching Waveforms







*Includes all probe and jig capacitance Figure 4. Test Circuit

MC74VHC32

ORDERING INFORMATION

Device	Package	Shipping [†]
MC74VHC32DR2G	SOIC-14	2500 Unite / Tana & Baal
NLV74VHC32DR2G*	(Pb-Free)	2500 Units / Tape & Reel
MC74VHC32DTG		96 Units / Rail
MC74VHC32DTR2G	TSSOP-14 (Pb-Free)	2500 Units / Tape & Reel
NLV74VHC32DTR2G*		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable.

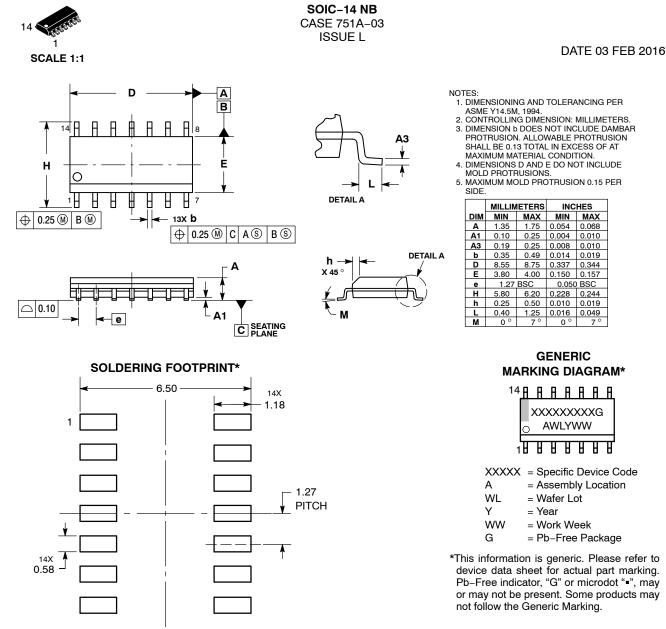
DUSEM

0.068

0.019

0.344

0.244



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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DATE 03 FEB 2016

STYLE 1: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 2: CANCELLED	STYLE 3: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE	STYLE 4: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 8. CATHODE 9. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE
STYLE 5:	STYLE 6:	STYLE 7:	STYLE 8:
PIN 1. COMMON CATHODE	PIN 1. CATHODE	PIN 1. ANODE/CATHODE	PIN 1. COMMON CATHODE
2. ANODE/CATHODE	2. CATHODE	2. COMMON ANODE	2. ANODE/CATHODE
3. ANODE/CATHODE	3. CATHODE	3. COMMON CATHODE	3. ANODE/CATHODE
4. ANODE/CATHODE	4. CATHODE	4. ANODE/CATHODE	4. NO CONNECTION
5. ANODE/CATHODE	5. CATHODE	5. ANODE/CATHODE	5. ANODE/CATHODE
6. NO CONNECTION	6. CATHODE	6. ANODE/CATHODE	6. ANODE/CATHODE
7. COMMON ANODE	7. CATHODE	7. ANODE/CATHODE	7. COMMON ANODE
8. COMMON CATHODE	8. ANODE	8. ANODE/CATHODE	8. COMMON ANODE
9. ANODE/CATHODE	9. ANODE	10. ANODE/CATHODE	9. ANODE/CATHODE
10. ANODE/CATHODE	10. ANODE	11. COMMON CATHODE	10. ANODE/CATHODE
11. ANODE/CATHODE	11. ANODE	12. COMMON CATHODE	11. NO CONNECTION
12. ANODE/CATHODE	12. ANODE	13. ANODE/CATHODE	12. ANODE/CATHODE
13. NO CONNECTION	13. ANODE	14. ANODE/CATHODE	13. ANODE/CATHODE
14. COMMON ANODE	14. ANODE	14. ANODE/CATHODE	14. COMMON CATHODE

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